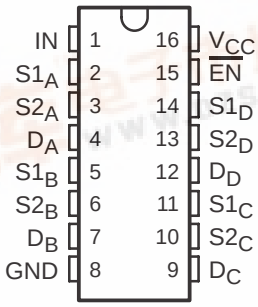
TS3V340
QUAD SPDT HIGH-BANDWIDTH VIDEO SWITCH WITH LOW AND FLAT ON-STATE RESISTANCE

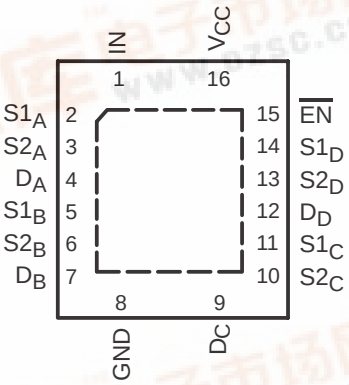
SCDS172A - JULY 2004 – REVISED DECEMBER 2004

- Low Differential Gain and Phase (D_G = 0.2%, D_P = 0.1° Typ)
- Wide Bandwidth (B_W = 500 MHz Typ)
- Low Crosstalk (X_{TALK} = −80 dB Typ)
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low and Flat ON-State Resistance (r_{on} = 3 Ω Typ, $r_{on(flat)}$ = 1 Ω Typ)
- V_{CC} Operating Range From 3 V to 3.6 V
- I_{off} Supports Partial-Power-Down Mode Operation
- Data and Control Inputs Provide Undershoot Clamp Diode
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Suitable for Both RGB and Composite Video Switching

D, DBQ, DGV, OR PW PACKAGE
(TOP VIEW)



RGY PACKAGE
(TOP VIEW)



description/ordering information

The TI video switch TS3V340 is a 4-bit 1-of-2 multiplexer/demultiplexer with a single switch-enable ($\overline{EN}$) input. When $\overline{EN}$ is low, the switch is enabled, and the D port is connected to the S port. When $\overline{EN}$ is high, the switch is disabled, and the high-impedance state exists between the D and S ports. The select (IN) input controls the data path of the multiplexer/demultiplexer.

Low differential gain and phase makes this switch ideal for composite and RGB video applications. The device has a wide bandwidth and low crosstalk, making it suitable for high-frequency applications as well.

ORDERING INFORMATION

T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−40°C to 85°C	QFN − RGY	Tape and reel	TS3V340RGYR	TF340
	SOIC − D	Tube	TS3V340D	TS3V340
		Tape and reel	TS3V340DR	
	SSOP (QSOP) − DBQ	Tape and reel	TS3V340DBQR	TF340
	TSSOP − PW	Tube	TS3V340PW	TF340
		Tape and reel	TS3V340PWR	
	TVSOP − DGV	Tape and reel	TS3V340DGVR	TF340

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

description/ordering information (continued)

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. This switch maintains isolation during power off.

To ensure the high-impedance state during power up or power down, $\overline{EN}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE

INPUTS		INPUT/OUTPUT D	FUNCTION
$\overline{EN}$	IN		
L	L	S1	D port = S1 port
L	H	S2	D port = S2 port
H	X	Z	Disconnect

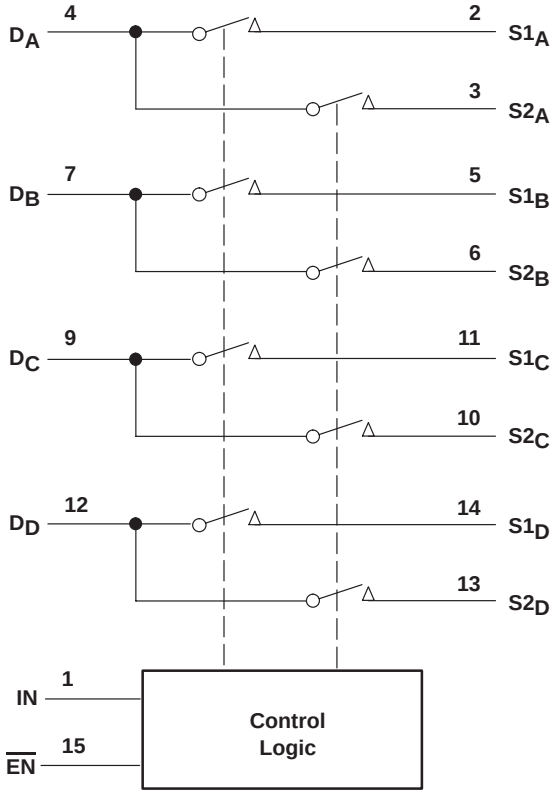
PIN DESCRIPTION

PIN NAME	DESCRIPTION
S1, S2	Analog video I/Os
D	Analog video I/Os
IN	Select input
$\overline{EN}$	Switch-enable input

PARAMETER DEFINITIONS

PARAMETER	DESCRIPTION
R_{ON}	Resistance between the D and S ports, with the switch in the ON state
I_{OZ}	Output leakage current measured at the D and S ports, with the switch in the OFF state
I_{OS}	Short-circuit current measured at the I/O pins
V_{IN}	Voltage at IN
V_{EN}	Voltage at $\overline{EN}$
C_{IN}	Capacitance at the control ($\overline{EN}$, IN) inputs
C_{OFF}	Capacitance at the analog I/O port when the switch is OFF
C_{ON}	Capacitance at the analog I/O port when the switch is ON
V_{IH}	Minimum input voltage for logic high for the control ($\overline{EN}$, IN) inputs
V_{IL}	Maximum input voltage for logic low for the control ($\overline{EN}$, IN) inputs
V_{IK}	I/O and control ($\overline{EN}$, IN) inputs diode clamp voltage
V_I	Voltage applied to the D or S pins when D or S is the switch input
V_O	Voltage applied to the D or S pins when D or S is the switch output
I_{IH}	Input high leakage current of the control ($\overline{EN}$, IN) inputs
I_{IL}	Input low leakage current of the control ($\overline{EN}$, IN) inputs
I_I	Current into the D or S pins when D or S is the switch input
I_O	Current into the D or S pins when D or S is the switch output
I_{off}	Output leakage current measured at the D or S ports, with V_{CC} = 0
t_{pds}	Propagation delay measured between $S1_X$ and $S2_X$ under the specified conditions, measured from 50% of the digital input to 90% of the analog output
B_W	Frequency response of the switch in the ON state, measured at −3 dB
X_{TALK}	Unwanted signal coupled from channel to channel. Measured in −dB. X_{TALK} = 20 log V_O/V_I. This is a nonadjacent crosstalk.
O_{IRR}	OFF isolation is the resistance (measured in −dB) between the input and output with the switch OFF.
D_G	Magnitude variation between analog input and output pins when the switch is ON and the DC offset of composite video signal varies at the analog input pin. In NTSC standard, the frequency of the video signal is 3.58 MHz, and DC offset is from 0 to 0.714 V.
D_P	Phase variation between analog input and output pins when the switch is ON and the DC offset of composite video signal varies at the analog input pin. In NTSC standard, the frequency of the video signal is 3.58 MHz, and DC offset is from 0 to 0.714 V.
I_{CC}	Static power-supply current
I_{CCD}	Variation of I_{CC} for a change in frequency in the control ($\overline{EN}$, IN) inputs
ΔI_{CC}	Increase in supply current for each control input that is at the specified voltage level, rather than V_{CC} or GND

functional diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . −0.5 V to 4.6 V
Control input voltage range, V_{IN} (see Notes 1 and 2) . . . . . −0.5 V to 7 V
Switch I/O voltage range, $V_{I/O}$ (see Notes 1, 2, and 3) . . . . . −0.5 V to 7 V
Control input clamp current, I_{IK} (V_{IN} < 0) . . . . . −50 mA
I/O port clamp current, $I_{I/OK}$ ($V_{I/O}$ < 0) . . . . . −50 mA
ON-state switch current, $I_{I/O}$ (see Note 4) . . . . . ±128 mA
Continuous current through V_{CC} or GND terminals . . . . . ±100 mA
Package thermal impedance, θ_{JA} (see Note 5): D package . . . . . 73°C/W
(see Note 5): DBQ package . . . . . 90°C/W
(see Note 5): DGV package . . . . . 120°C/W
(see Note 5): PW package . . . . . 108°C/W
(see Note 6): RGY package . . . . . 39°C/W
Storage temperature range, T_{stg} . . . . . −65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to ground, unless otherwise specified.
2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
3. V_I and V_O are used to denote specific conditions for $V_{I/O}$.
4. I_I and I_O are used to denote specific conditions for $I_{I/O}$.
5. The package thermal impedance is calculated in accordance with JESD 51-7.
6. The package thermal impedance is calculated in accordance with JESD 51-5.

recommended operating conditions (see Note 7)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	3	3.6	V
V_{IH}	High-level control input voltage ($\overline{EN}$, IN)	2	5.5	V
V_{IL}	Low-level control input voltage ($\overline{EN}$, IN)	0	0.8	V
V_O	Analog I/O voltage	0	5.5	V
T_A	Operating free-air temperature	−40	85	°C

NOTE 7: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted)†

PARAMETER		TEST CONDITIONS				MIN	TYP‡	MAX	UNIT
V_{IK}	$\overline{EN}$, IN	V_{CC} = 3 V,	I_{IN} = −18 mA					−1.8	V
I_{IH}	$\overline{EN}$, IN	V_{CC} = 3.6 V,	V_{IN} and V_{EN} = 5.5 V					±1	µA
I_{IL}	$\overline{EN}$, IN	V_{CC} = 3.6 V,	V_{IN} and V_{EN} = GND					±1	µA
I_{OZ}§		V_{CC} = 3.6 V,	V_O = 0 to 5.5 V,	V_I = 0,	Switch OFF			±1	µA
I_{OS}¶		V_{CC} = 3.6 V,	V_O = 0.5 V_{CC},	V_I = 0,	Switch ON	50			mA
I_{off}		V_{CC} = 0,	V_O = 0 to 5.5 V,	V_I = 0				1	µA
I_{CC}		V_{CC} = 3.6 V,	$I_{I/O}$ = 0,	Switch ON or OFF			0.7	1.5	mA
ΔI_{CC}	$\overline{EN}$, IN	V_{CC} = 3.6 V,	One input at 3 V,	Other inputs at V_{CC} or GND				30	µA
I_{CCD}		V_{CC} = 3.6 V, D and S ports open,	V_{EN} = GND, V_{IN} input switching 50% duty cycle					0.35	mA/ MHz
C_{IN}	$\overline{EN}$, IN	V_{IN} or V_{EN} = 5.5 V,	3.3 V or 0,	f = 1 MHz			2.5	3.5	pF
C_{OFF}	D port	V_I = 5.5 V, 3.3 V, or 0,	f = 1 MHz,	Outputs open,	Switch OFF		5.5	7	pF
	S port						3.5	5	
C_{ON}		V_I = 5.5 V, 3.3 V, or 0,	f = 1 MHz,	Outputs open,	Switch ON		10.5	14	pF
r_{on}#		V_{CC} = 3 V	V_I = 1 V,	I_O = 13 mA			3	6	Ω
			V_I = 2 V,	I_O = 26 mA			3	6	
$r_{on(flat)}$‖		V_{CC} = 3.3 V,	V_I = 0 to V_{CC},	I_O = 26 mA			1		Ω

† V_I, V_O, I_I, and I_O refer to I/O pins.
‡ All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.
§ For I/O ports, the parameter I_{OZ} includes the input leakage current.
¶ The I_{OS} test is applicable to only one ON channel at a time. The duration of this test is less than 1 s.
# Measured by the voltage drop between the D and S terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (D or S) terminals.
‖ $r_{on(flat)}$ is the difference of r_{on} in a given channel at specified voltages.

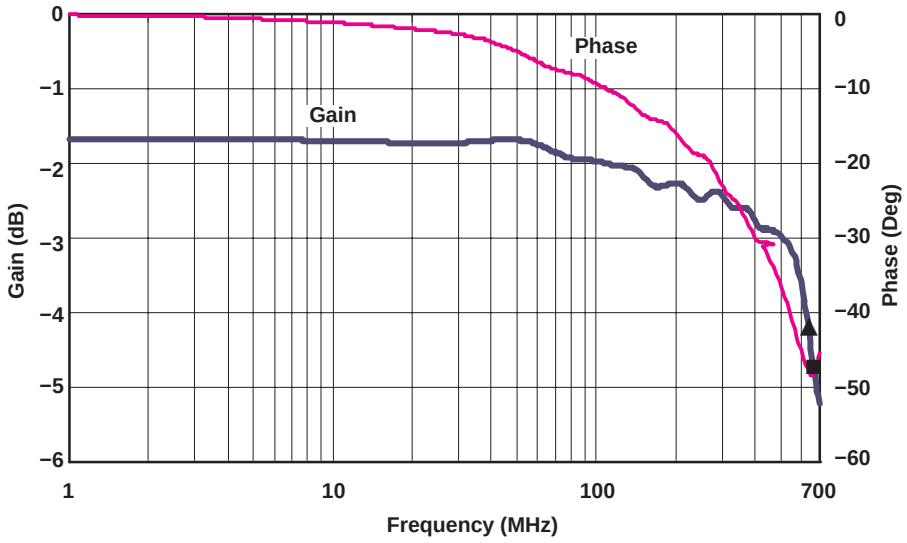
switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V, R_L = 75 Ω, C_L = 20 pF (unless otherwise noted) (see Figures 6 and 7)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP	MAX	UNIT
$t_{pd(s)}$	IN	D		2	5	ns
t_{ON}	IN or $\overline{EN}$	S		4	7	ns
t_{OFF}	IN or $\overline{EN}$	S		2	7	ns

dynamic characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted)

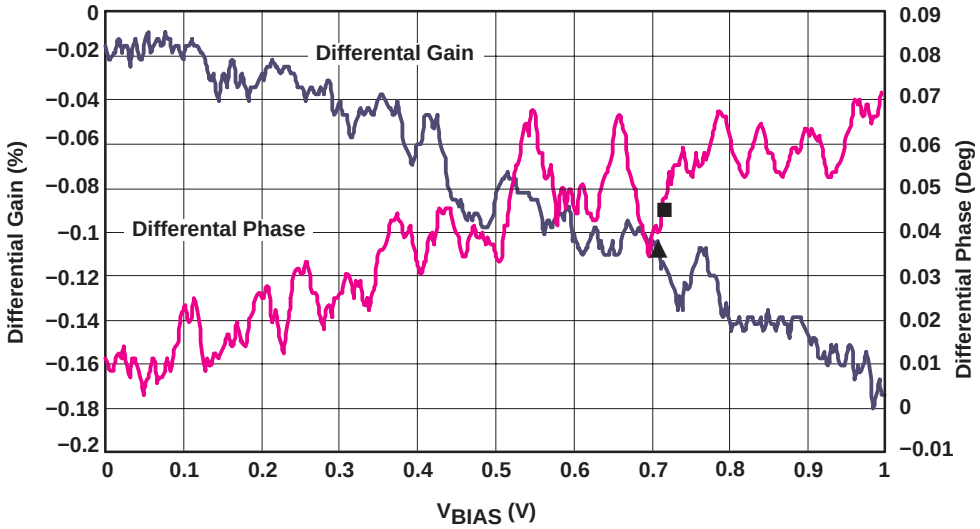
PARAMETER	TEST CONDITIONS				TYP‡	UNIT
D_G☆	R_L = 150 Ω,	f = 3.58 MHz,	See Figure 7		0.2	%
D_P☆	R_L = 150 Ω,	f = 3.58 MHz,	See Figure 7		0.1	°
B_W	R_L = 150 Ω,	See Figure 8			500	MHz
X_{TALK}	R_L = 150 Ω,	f = 10 MHz,	R_{IN} = 10 Ω,	See Figure 9	−80	dB
O_{IRR}	R_L = 150 Ω,	f = 10 MHz,	See Figure 10		−60	dB

‡ All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.
☆ D_G and D_P are expressed in absolute magnitude.



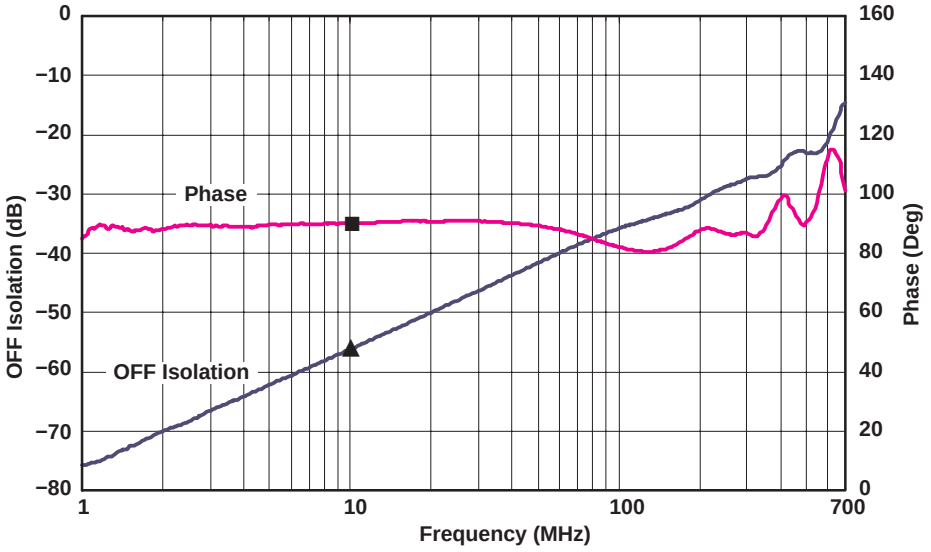
▲ Gain −3 dB at 627 MHz
■ Phase at −3-dB Frequency, −47 Deg

Figure 1. Gain/Phase vs Frequency



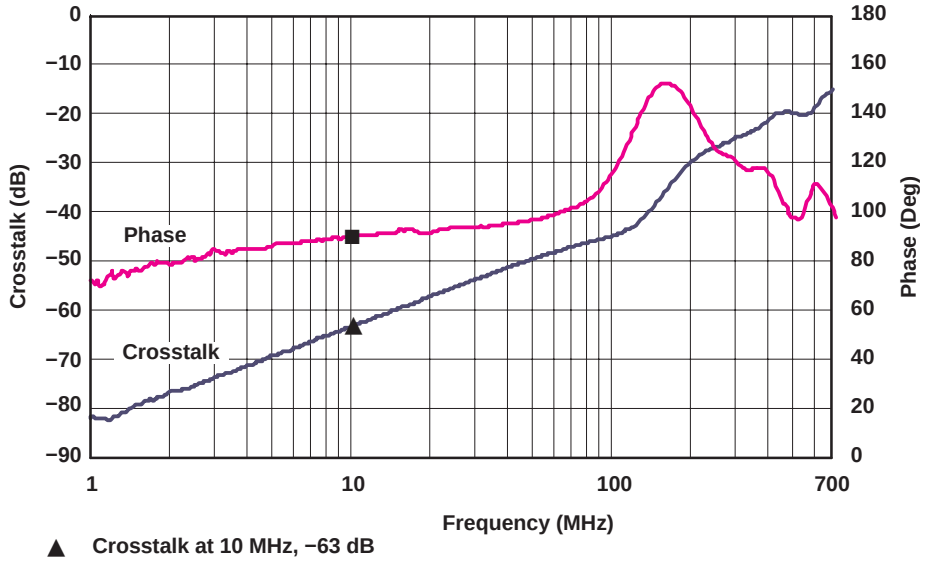
▲ Differential Gain at 0.714 V, −0.11%
■ Differential Phase at 0.714 V, 0.0466 Deg

Figure 2. Differential Gain/Phase vs V_{BIAS}



▲ OFF Isolation at 10 MHz, −56 dB
■ Phase at 10 MHz, 90 Deg

Figure 3. OFF Isolation vs Frequency



▲ Crosstalk at 10 MHz, −63 dB
■ Phase at 10 MHz, 90 Deg

Figure 4. Crosstalk vs Frequency

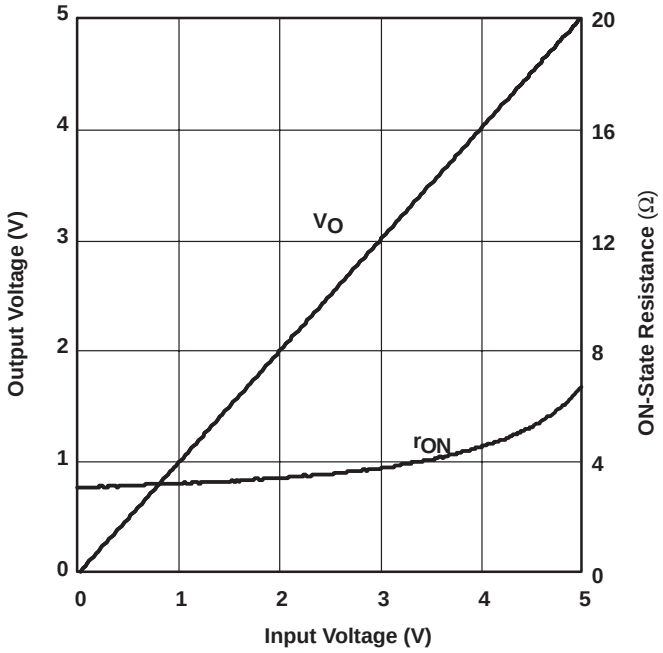
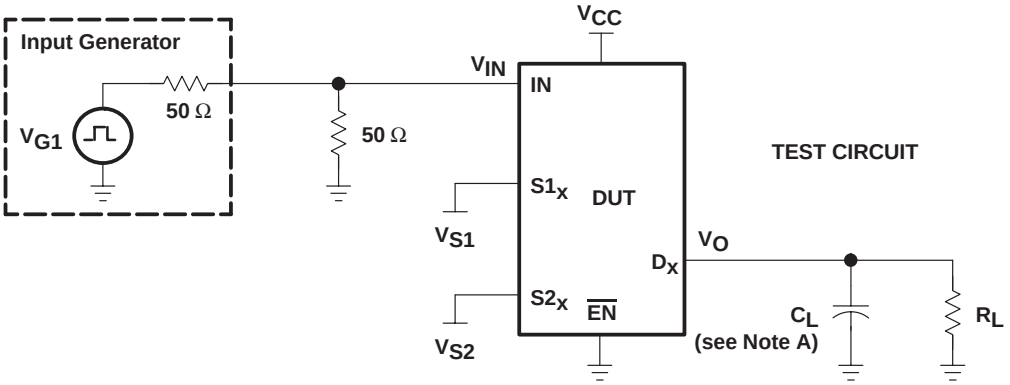
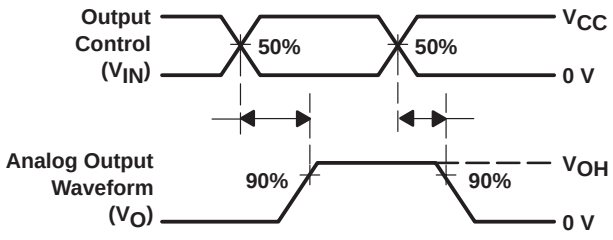


Figure 5. Output Voltage/ON-State Resistance vs Input Voltage

PARAMETER MEASUREMENT INFORMATION



TEST	V_{CC}	R_L	C_L	V_{S1}	V_{S2}
t_{pds}	3.3 V ± 0.3 V	75	20 pF	GND	V_{CC}
	3.3 V ± 0.3 V	75	20 pF	V_{CC}	GND

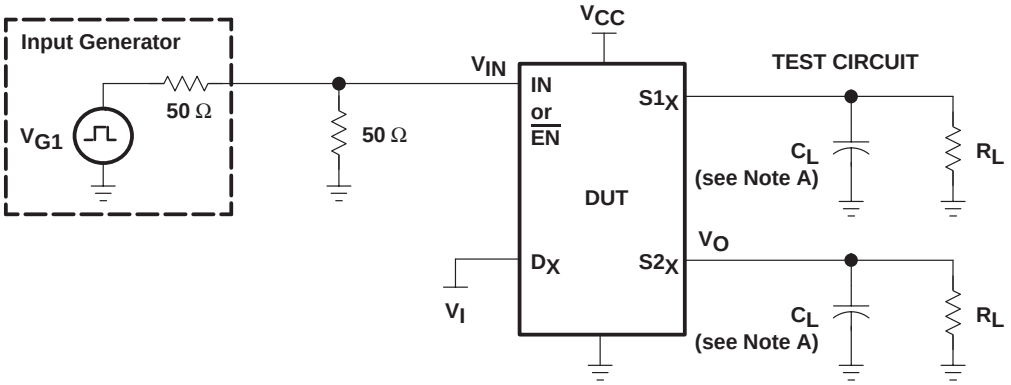


VOLTAGE WAVEFORMS
$t_{pd(s)}$ TIMES

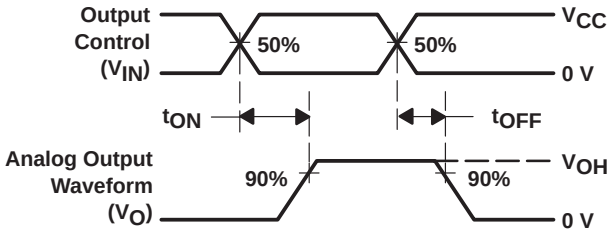
NOTES: A. C_L includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
C. The outputs are measured one at a time, with one transition per measurement.

Figure 6. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



TEST	V_{CC}	R_L	C_L	V_I
t_{ON}/t_{OFF}	3.3 V ± 0.3 V	75 Ω	20 pF	V_{CC}

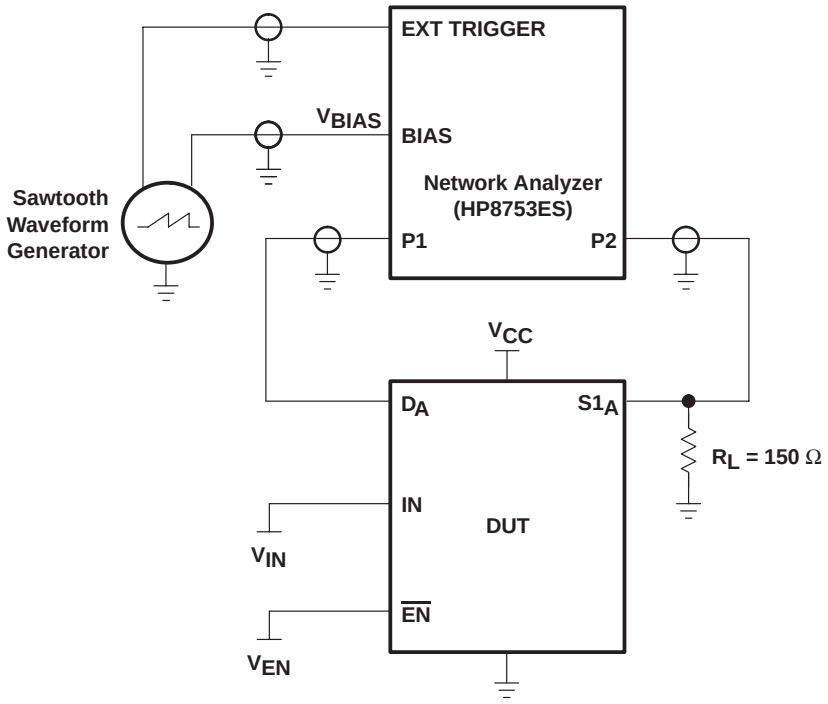


VOLTAGE WAVEFORMS
t_{ON} AND t_{OFF} TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
C. The outputs are measured one at a time, with one transition per measurement.

Figure 7. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



NOTE: For additional information on measurement method, refer to the TI application report, *Measuring Differential Gain and Phase*, literature number SLOA040.

Figure 8. Test Circuit for Differential Gain/Phase Measurement

Differential gain and phase is measured at the output of the ON channel. For example, when V_{IN} = 0, V_{EN} = 0, and D_A is the input, the output is measured at $S1_A$.

HP8753ES setup

Average = 20
RBW = 300 Hz
ST = 1.381 s
P1 = −7 dBM
CW frequency = 3.58 MHz

sawtooth waveform generator setup

V_{BIAS} = 0 to 1 V
Frequency = 0.905 Hz

PARAMETER MEASUREMENT INFORMATION

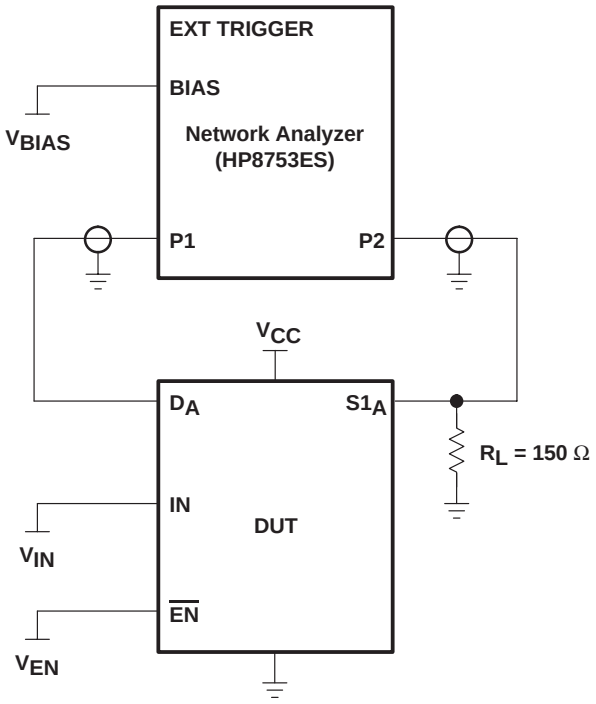


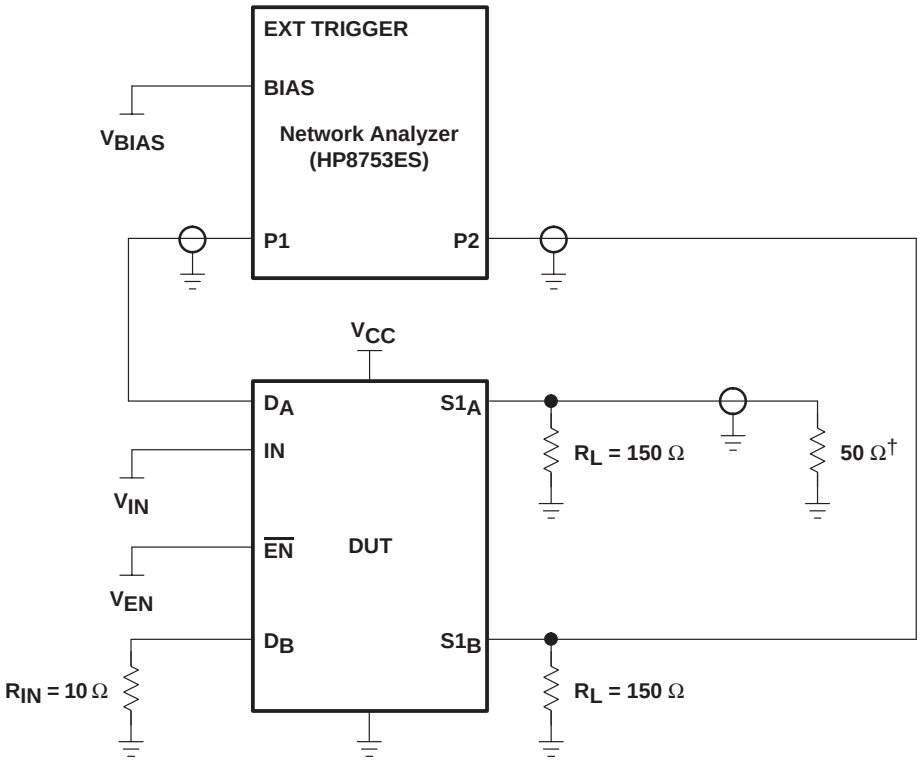
Figure 9. Test Circuit for Frequency Response (B_W)

The frequency response is measured at the output of the ON channel. For example, when V_{IN} = 0, V_{EN} = 0, and D_A is the input, the output is measured at $S1_A$. All unused analog I/O ports are left open.

HP8753ES setup

Average = 4
RBW = 3 kHz
V_{BIAS} = 0.35 V
ST = 2 s
P1 = 0 dBM

PARAMETER MEASUREMENT INFORMATION



† A 50-Ω termination resistor is needed for the network analyzer.

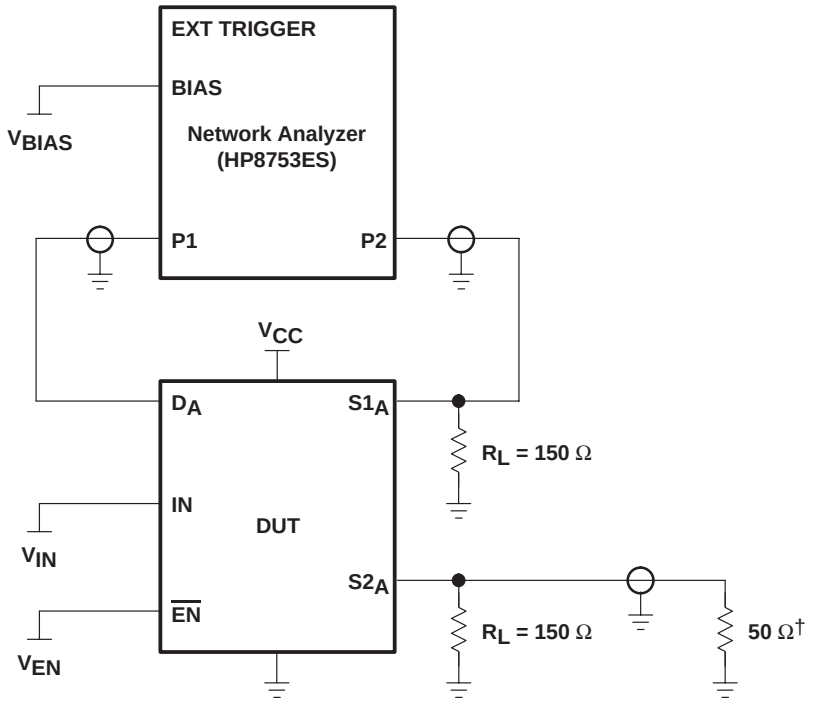
Figure 10. Test Circuit for Crosstalk (X_{TALK})

The crosstalk is measured at the output of the nonadjacent ON channel. For example, when V_{IN} = 0, V_{EN} = 0, and D_A is the input, the output is measured at $S1_B$. All unused analog input (D) ports and output (S) ports are connected to GND through 10-Ω and 50-Ω pulldown resistors, respectively.

HP8753ES setup

Average = 4
RBW = 3 kHz
V_{BIAS} = 0.35 V
ST = 2 s
P1 = 0 dBM

PARAMETER MEASUREMENT INFORMATION



† A 50-Ω termination resistor is needed for the network analyzer.

Figure 11. Test Circuit for OFF Isolation (O_{IRR})

The OFF isolation is measured at the output of the OFF channel. For example, when $V_{IN} = V_{CC}$, $V_{EN} = 0$, and D_A is the input, the output is measured at $S1_A$. All unused analog input (D) ports are left open, and output (S) ports are connected to GND through 50-Ω pulldown resistors.

HP8753ES setup

Average = 4
RBW = 3 kHz
V_{BIAS} = 0.35 V
ST = 2 s
P1 = 0 dBM

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
TS3V340D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340DBQR	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TS3V340DBQRE4	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TS3V340DE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340DGVR	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340DGVRE4	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340DRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3V340RGYR	ACTIVE	QFN	RGY	16	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

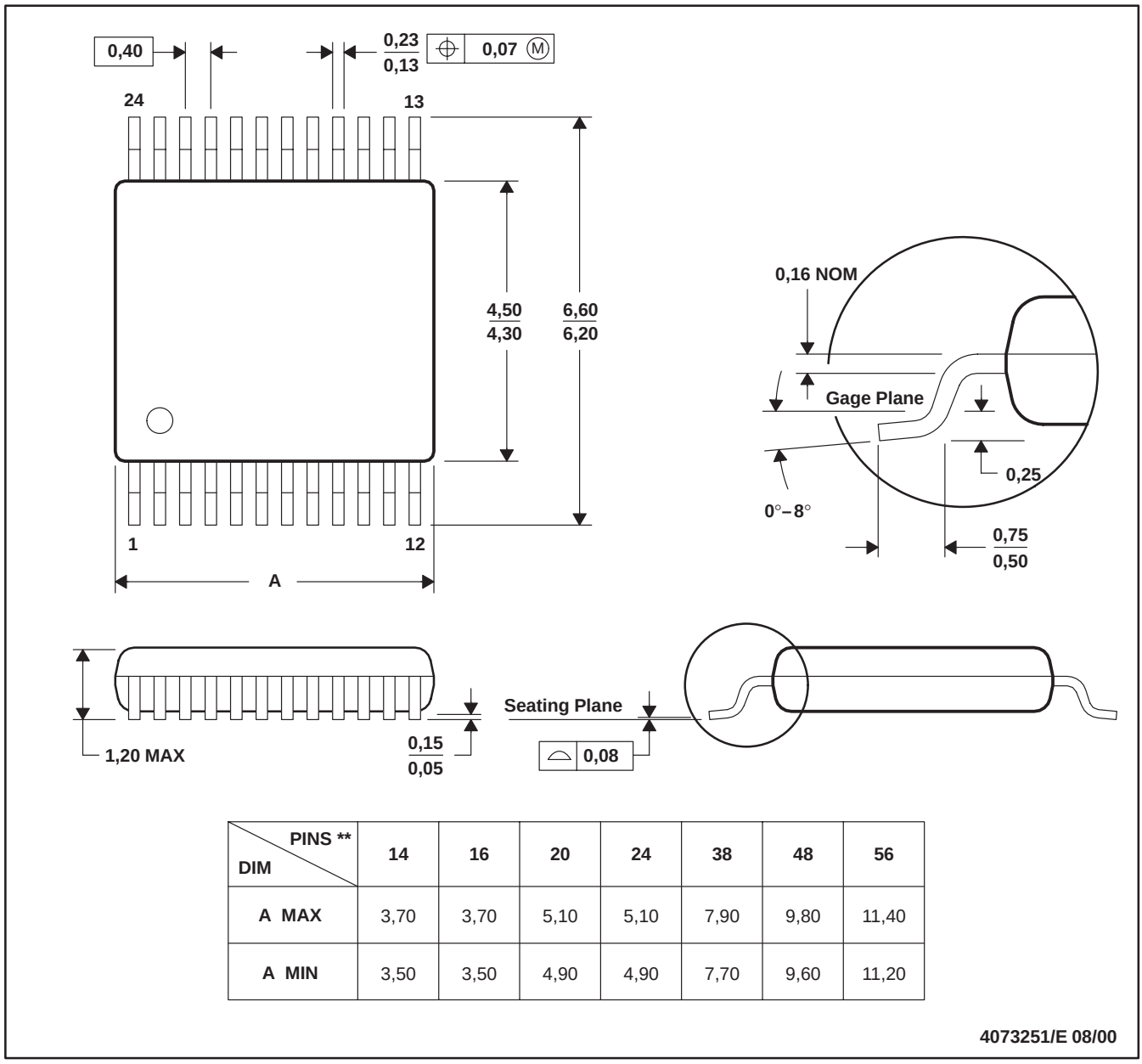
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

MPDS006C – FEBRUARY 1996 – REVISED AUGUST 2000

DGV (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

24 PINS SHOWN



DIM \ PINS **	14	16	20	24	38	48	56
A MAX	3,70	3,70	5,10	5,10	7,90	9,80	11,40
A MIN	3,50	3,50	4,90	4,90	7,70	9,60	11,20

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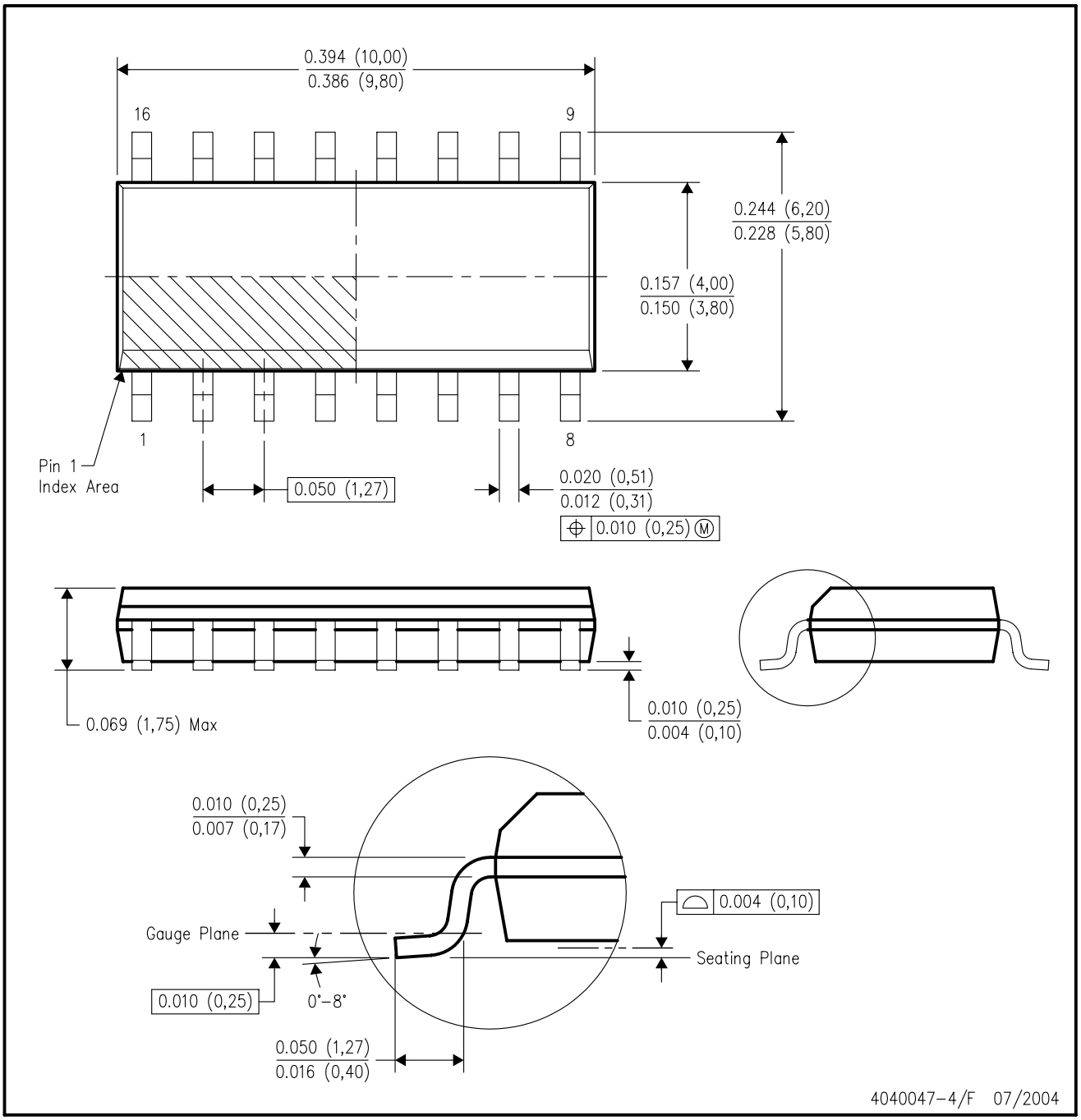
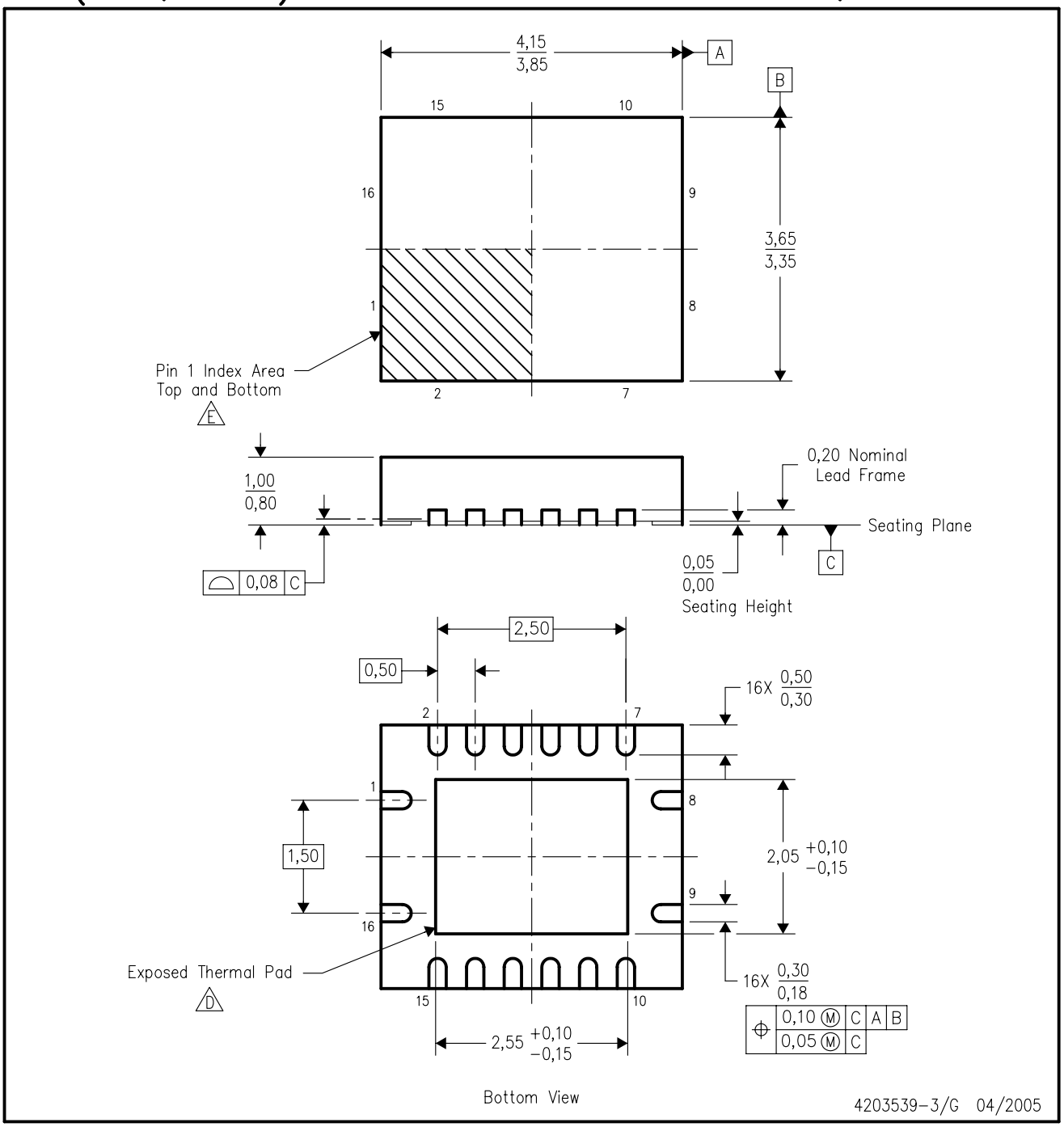
NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
D. Falls within JEDEC: 24/48 Pins – MO-153
14/16/20/56 Pins – MO-194

D (R–PDSO–G16) PLASTIC SMALL–OUTLINE PACKAGE



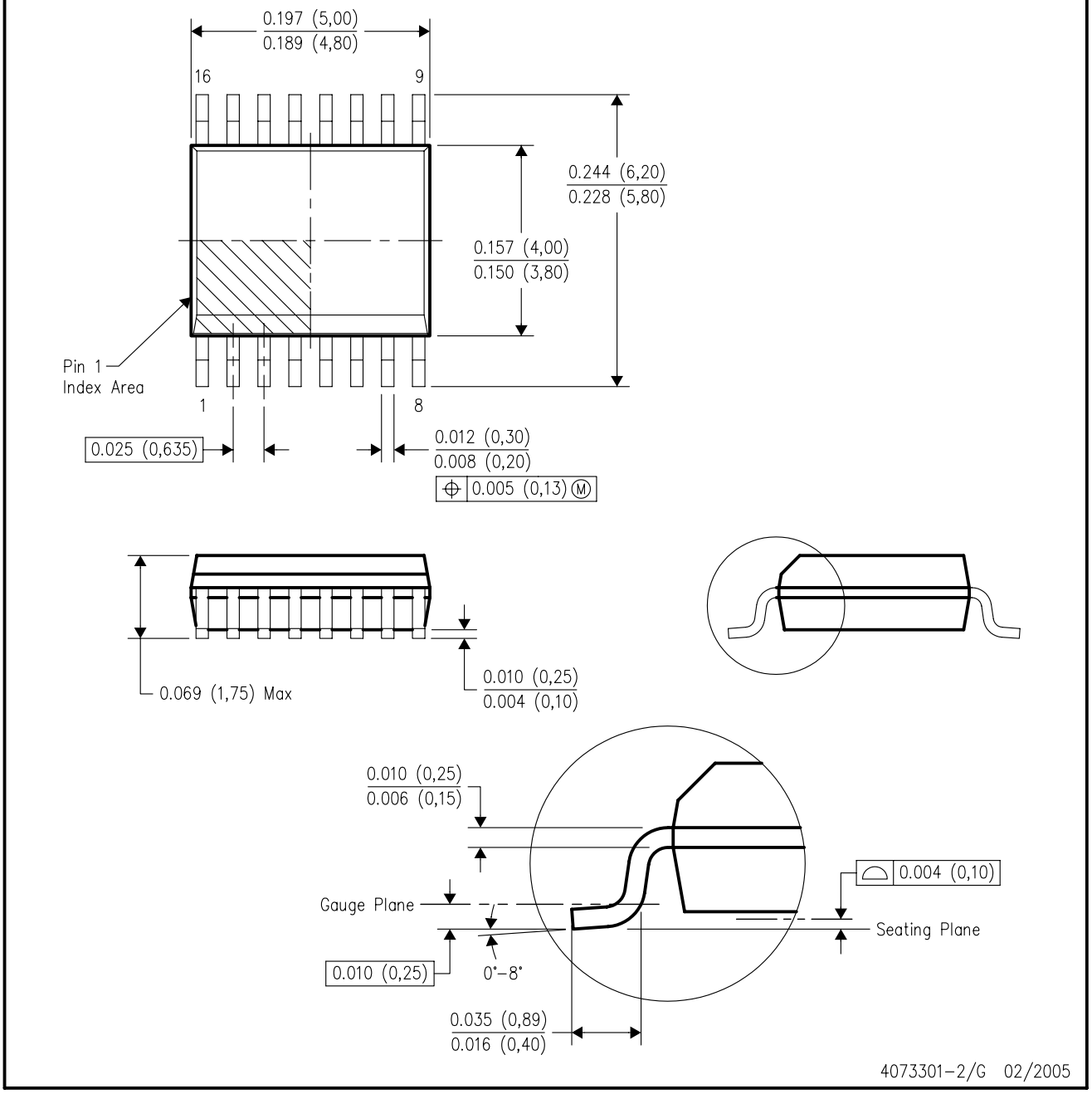
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS–012 variation AC.

RGY (R–PQFP–N16) PLASTIC QUAD FLATPACK



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No–Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
E. Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
F. Package complies to JEDEC MO–241 variation BB.

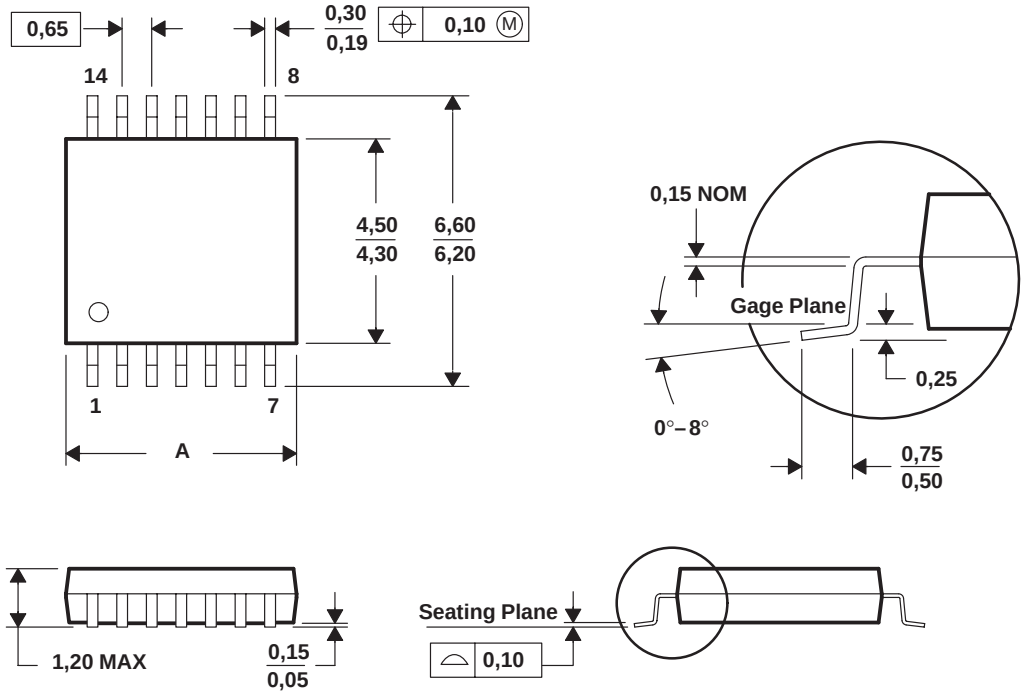
DBQ (R–PDSO–G16) PLASTIC SMALL–OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
D. Falls within JEDEC MO–137 variation AB.

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

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NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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